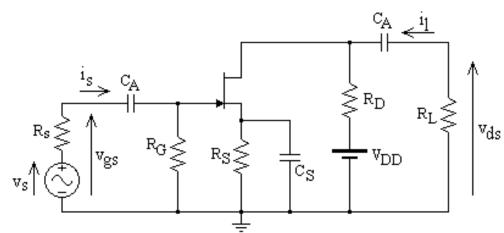
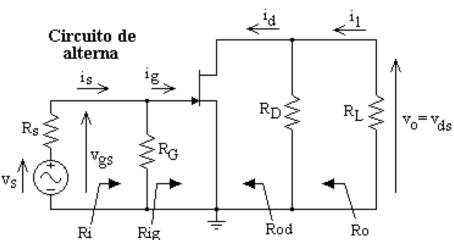
Configuraciones de un amplificador

Source común





$$vo = vds = -id(RD//RL)$$

 $vi = vgs$

$$A_{v} = \frac{v_{ds}}{v_{gs}} = -g_{m} \left(r_{ds} // R_{D} // R_{L} \right)$$

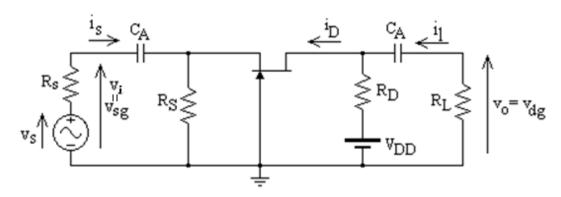
$$A_{v} = \frac{v_{ds}}{v_{gs}} = -g_{m}R_{Do}$$

$$R_{ig} = \frac{v_{gs}}{i_g} = r_{gs}$$

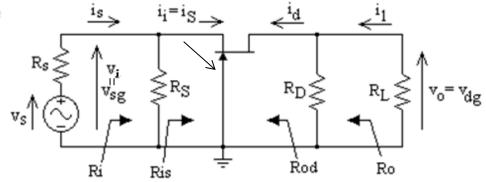
$$R_{od} = v_{dp}/i_{dp} = r_{ds}$$

 $\Rightarrow R_o = R_D/R_{od} \cong R_D$

Gate común:



Circuito de alterna



$$vo = vdg = -id(RD//RL)$$

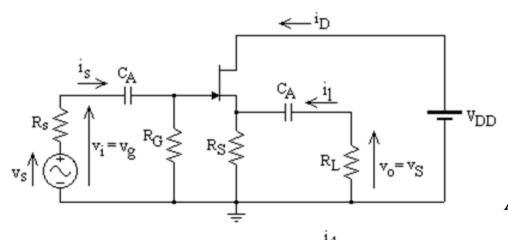
 $vi = -vgs$

$$A_{v} = \frac{v_{dg}}{v_{sg}} = g_{m}R_{Da}$$

$$R_{is} = \frac{v_{sg}}{i_s} = \frac{1}{g_m} = \frac{-vgs}{-id}$$

$$R_{od} = v_{dp}/i_{dp} = r_{ds} (1 + g_m R_{Ss})$$

Drain común (seguidor):



$$vo = vs = id (RS//RL)$$

 $vi = vgs + id (RS//RL)$

$$A_{v} = \frac{v_{S}}{v_{g}} = \frac{\beta_{FET} R_{Sa}}{r_{gs} + \beta_{FET} R_{Sa}} = \frac{g_{m} R_{Sa}}{1 + g_{m} R_{Sa}}$$

$$R_{os} = \frac{1}{g_m} + \frac{R_s // R_G}{\beta_{FET}} \cong \frac{1}{g_m}$$

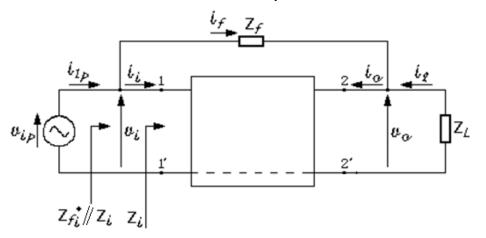
$$R_{ig} = \frac{v_g}{i_g} = r_{gs} + \beta_{FET} (R_S // R_L) = r_{gs} + g_m r_{gs} R_{Sa} = r_{gs} (1 + g_m R_{Sa})$$

Resumiendo:

SC
$$Av$$
 Ri Ro SC $<<-1$ $\uparrow\uparrow$ \uparrow \uparrow \uparrow $\downarrow\downarrow$ \uparrow $\downarrow\downarrow$ $\downarrow\downarrow$ \uparrow $\downarrow\downarrow$

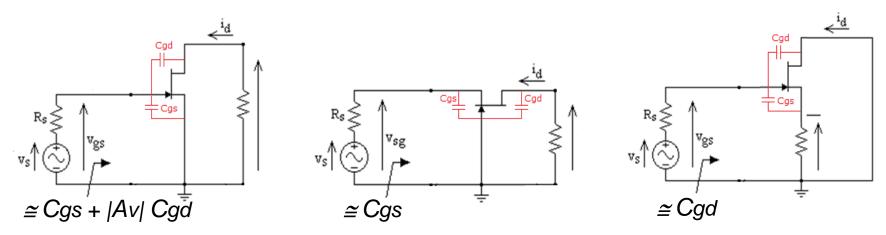
¿Cómo responden en frecuencia? (análisis cualitativo)

Recordando la reflexión por relación de v:



Con Av << - 1 Si $Zf \rightarrow C \rightarrow Zf^* \cong 1 / j\omega C |Av|$

Con Av \cong 1
Zf* $\rightarrow \infty$



→ el **SC** es el tendrá menor ancho de banda

